## NSN 5961-00-454-6864

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-454-6864 **Inclosure Material:** Metal **Overall Length:** 0.085 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 100.00 milliamperes base current, dc and 400.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 400.0 milliwatts collector power dissipation **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5516 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**